

1. Global joint venture starts operations as WeEn Semiconductors

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Thank you for your cooperation and understanding,

WeEn Semiconductors





1. General description

Planar passivated four quadrant triac in a SOT428 (DPAK) surface-mountable plastic package intended for use in general purpose bidirectional switching and phase control applications.

2. Features and benefits

- High blocking voltage capability
- Less sensitive gate for improved noise immunity
- Planar passivated for voltage ruggedness and reliability
- Surface mountable package
- Triggering in all four quadrants

3. Applications

- General purpose motor control
- General purpose switching

4. Quick reference data

| Table 1. Qui | ck reference data | | | | | |
|---------------------|--|---|-----|-----|-----|------|
| Symbol | Parameter | Conditions | Min | Тур | Мах | Unit |
| V _{DRM} | repetitive peak off- state voltage | | - | - | 800 | V |
| I _{TSM} | non-repetitive peak on- state current | full sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 20 \text{ ms}; \text{ Fig. 4}; \text{ Fig. 5}$ | - | - | 25 | A |
| I _{T(RMS)} | RMS on-state current | full sine wave; T _{mb} ≤ 107 °C; <u>Fig. 1;</u> <u>Fig. 2; Fig. 3</u> | - | - | 4 | A |
| Static charact | eristics | | | | | |
| I _{GT} | gate trigger current | V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 7</u> | - | 5 | 35 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 7</u> | - | 8 | 35 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 7</u> | - | 11 | 35 | mA |





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| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|--------|-----------|--|-----|-----|-----|------|
| | | V _D = 12 V; I _T = 0.1 A; T2- G+; | - | 30 | 70 | mA |
| | | T _j = 25 °C; <u>Fig. 7</u> | | | | |

5. Pinning information

| Table 2. | Pinning | information | | |
|----------|---------|-----------------------------------|--------------------|----------------|
| Pin | Symbol | Description | Simplified outline | Graphic symbol |
| 1 | T1 | main terminal 1 | mb | T2 |
| 2 | T2 | main terminal 2 | | sym051 |
| 3 | G | gate | | |
| mb | T2 | mounting base; main terminal 2 | DPAK (SOT428) | |

6. Ordering information

| Table 3. Ordering in | formation | | |
|----------------------|-----------|---|---------|
| Type number | Package | | |
| | Name | Description | Version |
| BT136S-800 | DPAK | plastic single-ended surface-mounted package (DPAK); 3 leads (one lead cropped) | SOT428 |

7. Limiting values

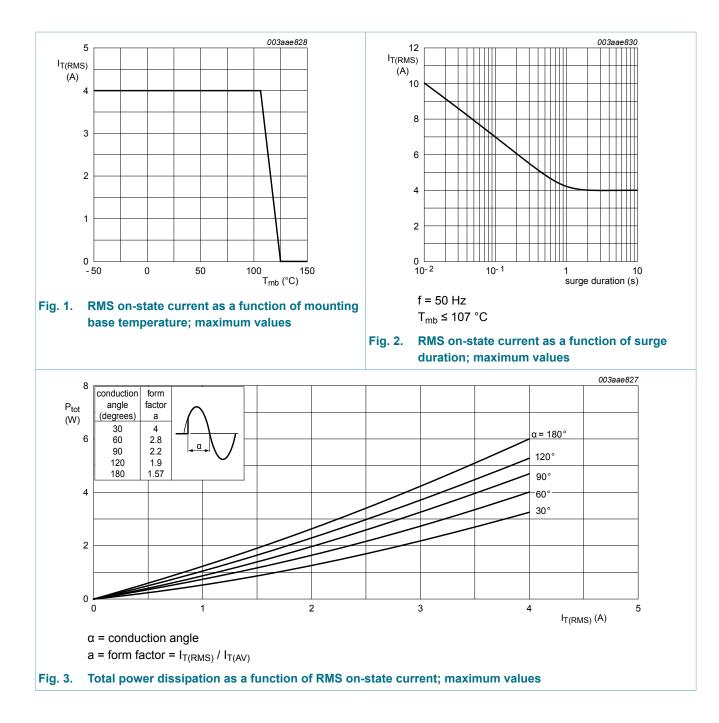
Table 4.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|---------------------|--------------------------------------|--|-----|-----|------------------|
| V _{DRM} | repetitive peak off-state voltage | | - | 800 | V |
| I _{T(RMS)} | RMS on-state current | full sine wave; $T_{mb} \le 107 \text{ °C}$; Fig. 1; Fig. 2; Fig. 3 | - | 4 | A |
| I _{TSM} | non-repetitive peak on-state current | full sine wave; $T_{j(init)} = 25 \text{ °C}$; $t_p = 20 \text{ ms}$; <u>Fig. 4</u> ; <u>Fig. 5</u> | - | 25 | A |
| | | full sine wave; $T_{j(init)} = 25 \text{ °C}$; $t_p = 16.7 \text{ ms}$ | - | 27 | A |
| l ² t | I2t for fusing | t _p = 10 ms; SIN | - | 3.1 | A ² s |
| dl _T /dt | rate of rise of on-state current | $I_T = 6 \text{ A}; I_G = 0.2 \text{ A}; dI_G/dt = 0.2 \text{ A}/\mu\text{s};$ T2+ G+ | - | 50 | A/µs |
| | | $I_T = 6 \text{ A}; I_G = 0.2 \text{ A}; dI_G/dt = 0.2 \text{ A}/\mu\text{s};$ T2+ G- | - | 50 | A/µs |
| | | $I_T = 6 \text{ A}; I_G = 0.2 \text{ A}; dI_G/dt = 0.2 \text{ A}/\mu\text{s};$ T2- G- | - | 50 | A/µs |
| | | $I_T = 6 \text{ A}; I_G = 0.2 \text{ A}; dI_G/dt = 0.2 \text{ A}/\mu\text{s};$ T2- G+ | - | 10 | A/µs |
| I _{GM} | peak gate current | | - | 2 | А |
| P _{GM} | peak gate power | | - | 5 | W |
| P _{G(AV)} | average gate power | over any 20 ms period | - | 0.5 | W |
| T _{stg} | storage temperature | | -40 | 150 | °C |
| Tj | junction temperature | | - | 125 | °C |

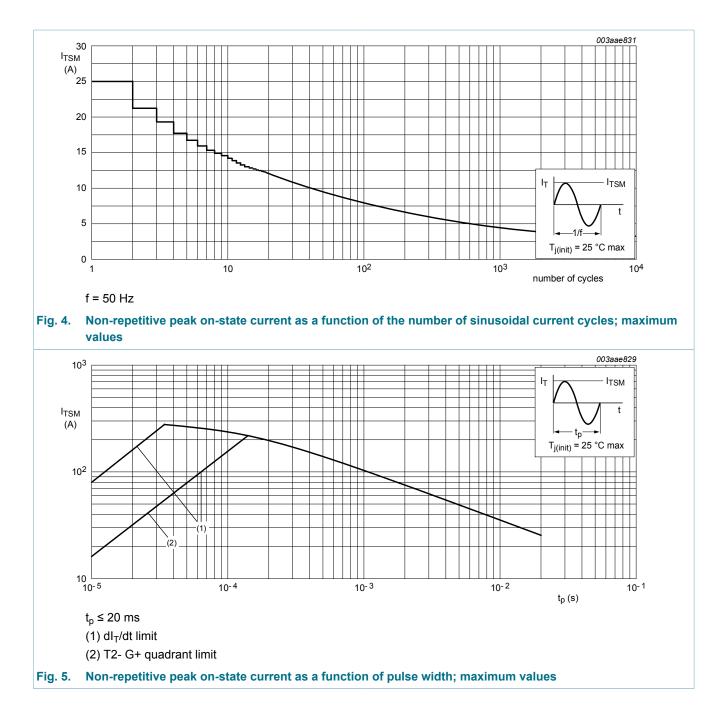
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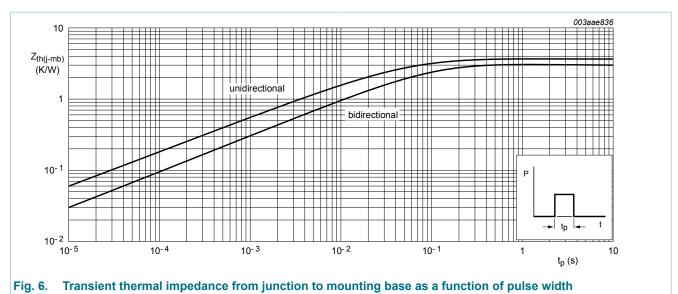
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8. Thermal characteristics

| Table 5. 1 | Thermal characteristics | | | | | |
|-----------------------|---|--|-----|-----|-----|------|
| Symbol | Parameter | Conditions | Min | Тур | Мах | Unit |
| R _{th(j-mb)} | thermal resistance | half cycle; Fig. 6 | - | - | 3.7 | K/W |
| | from junction to mounting base | full cycle; <u>Fig. 6</u> | - | - | 3 | K/W |
| R _{th(j-a)} | thermal resistance from junction to ambient | in free air; printed circuit board (FR4) mounted; standard footprint, single- sided copper, tin-plated | - | 75 | - | K/W |



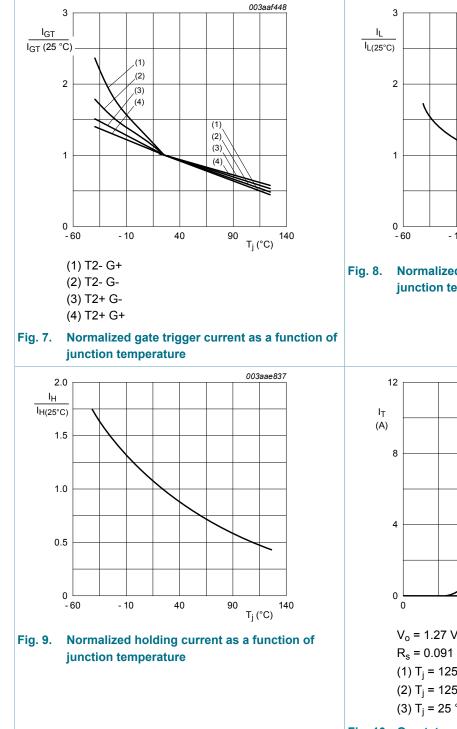
9. Characteristics

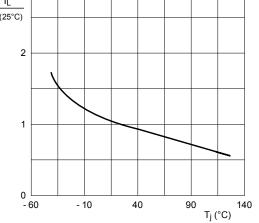
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------------|---------------------------------------|--|------|-----|-----|------|
| Static chara | octeristics | | | | | |
| I _{GT} | gate trigger current | V_D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 7</u> | - | 5 | 35 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 7</u> | - | 8 | 35 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 7</u> | - | 11 | 35 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2- G+; T _j = 25 °C; <u>Fig. 7</u> | - | 30 | 70 | mA |
| ΙL | latching current | V _D = 12 V; I _G = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 8</u> | - | 7 | 20 | mA |
| | | $V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T2+ G-};$ T _j = 25 °C; <u>Fig. 8</u> | - | 16 | 30 | mA |
| | | $V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T2- G-};$ T _j = 25 °C; Fig. 8 | - | 5 | 20 | mA |
| | | V _D = 12 V; I _G = 0.1 A; T2- G+; T _j = 25 °C; <u>Fig. 8</u> | - | 7 | 30 | mA |
| I _H | holding current | V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u> | - | 5 | 15 | mA |
| V _T | on-state voltage | I _T = 5 A; T _j = 25 °C; <u>Fig. 10</u> | - | 1.4 | 1.7 | V |
| V _{GT} | gate trigger voltage | V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; Fig. 11 | - | 0.7 | 1 | V |
| | | V _D = 400 V; I _T = 0.1 A; T _j = 125 °C; Fig. 11 | 0.25 | 0.4 | - | V |
| I _D | off-state current | V _D = 800 V; T _j = 125 °C | - | 0.1 | 0.5 | mA |
| Dynamic ch | aracteristics | II | I | | | |
| dV _D /dt | rate of rise of off-state voltage | V_{DM} = 536 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit | 100 | 250 | - | V/µs |
| dV _{com} /dt | rate of change of commutating voltage | V_D = 400 V; T _j = 95 °C; dI _{com} /dt = 1.8 A/ ms; I _T = 4 A; gate open circuit | - | 50 | - | V/µs |
| t _{gt} | gate-controlled turn-on time | I_{TM} = 6 A; V _D = 800 V; I _G = 0.1 A; dI _G / dt = 5 A/µs | - | 2 | - | μs |

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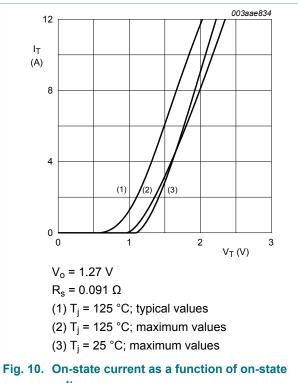
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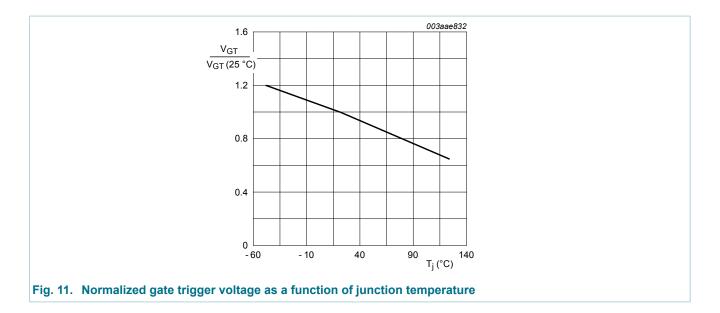




voltage

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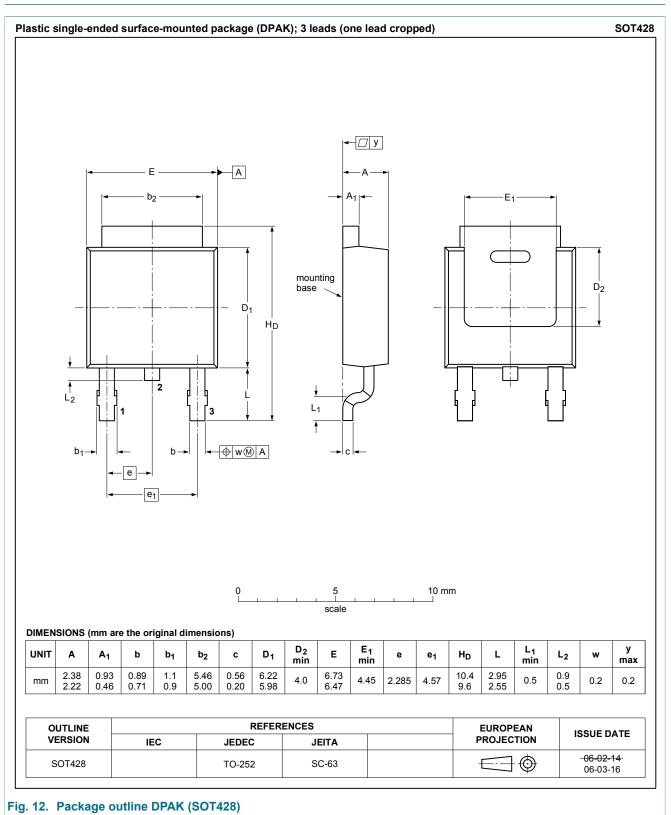


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10. Package outline

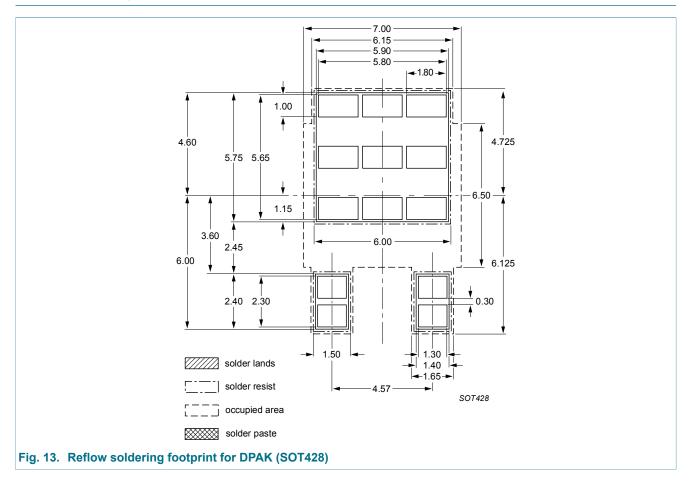


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11. Soldering



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12. Legal information

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|--------------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
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